NSN 5961-01-184-2826

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-184-2826 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 25.0 degrees celsius case **Special Features:** 0.250 in. Terminal Ig; junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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